SONY

SLD301XT

100mW High Power Laser Diode

Description

The SLD301XT allows independent thermal and electric design.
This laser diode has a built-in TE (Thermo Electric) cooler.

Features

- High power
  Recommended optical power output Po = 90mW
- Low operating current
- Flat Package with built-in photodiode, TE cooler and thermistor

Applications

- Solid state laser excitation
- Medical use

Structure

AlGaAs double-hetero-type laser diode

Operating Lifetime

MTTF 10,000H (effective value) at Po = 90mW, Tth = 25°C

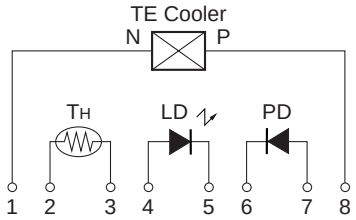
Absolute Maximum Ratings (Tth = 25°C)

• Optical power output	Po		100	mW
• Reverse voltage	V_R	LD	2	V
		PD	15	V
• Operating temperature (Tth)	Topr		–10 to +50	°C
• Storage temperature	Tstg		–40 to +85	°C

Warranty

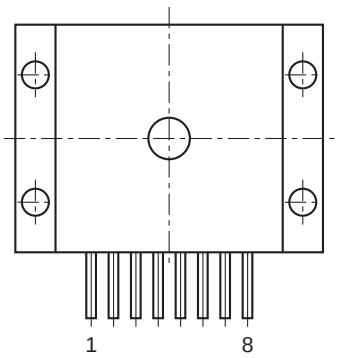
This warranty period shall be 90 days after receipt of the product or 1,000 hours operation time whichever is shorter.
Sony Quality Assurance Department shall analyze any product that fails during said warranty period, and if the analysis results show that the product failed due to material or manufacturing defects on the part of Sony, the product shall be replaced free of charge.
Laser diodes naturally have differing lifetimes which follow a Weibull distribution.
Special warranties are also available.

Equivalent Circuit



Pin Configuration (Top View)

No.	Function
1	TE cooler (negative)
2	Thermistor lead 1
3	Thermistor lead 2
4	Laser diode (anode)
5	Laser diode (cathode)
6	Photodiode (cathode)
7	Photodiode (anode)
8	TE cooler (positive)



E88059C02-PS

Electrical and Optical Characteristics (Tth: Thermistor temperature, Tth = 25°C)

Item		Symbol	Conditions	Min.	Typ.	Max.	Unit
Threshold current		Ith			150	200	mA
Operating current		Iop	P_O = 90mW		250	400	mA
Operating voltage		Vop	P_O = 90mW		1.9	3.0	V
Wavelength*		λp	P_O = 90mW	770		840	nm
Monitor current		Imon	P_O = 90mW V_R = 10V		0.15		mA
Radiation angle	Perpendicular	θ⊥	P_O = 90mW		28	40	degree
	Parallel	θ//			12	17	degree
Positional accuracy	Position	ΔX, ΔY	P_O = 90mW			±100	μm
	Angle	Δφ⊥				±3	degree
Differential efficiency		η_D	P_O = 90mW	0.65	0.9		mW/mA
Thermistor resistance		Rth	Tth = 25°C		10		kΩ

* **Wavelength Selection Classification**

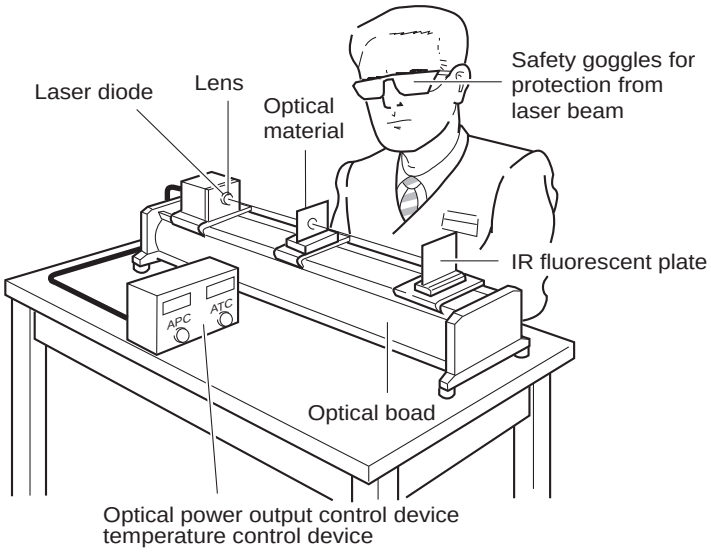
Type	Wavelength (nm)
SLD301XT-1	785 ± 15
SLD301XT-2	810 ± 10
SLD301XT-3	830 ± 10

Type	Wavelength (nm)
SLD301XT-21	798 ± 3
SLD301XT-24	807 ± 3
SLD301XT-25	810 ± 3

Handling Precautions

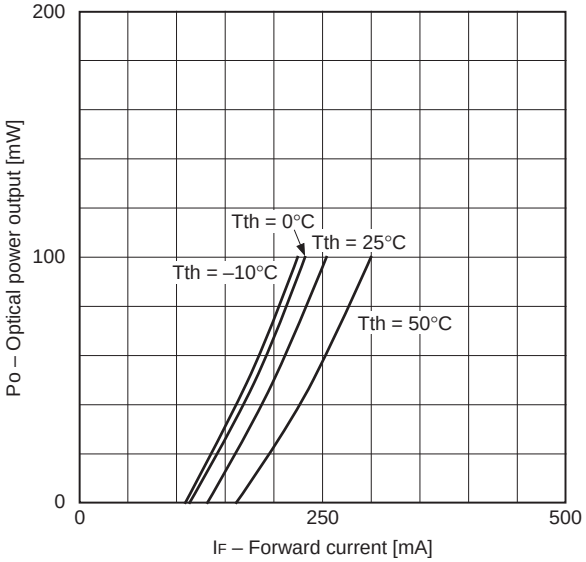
Eye protection against laser beams

The optical output of laser diodes ranges from several mW to 1W. However the optical power density of the laser beam at the diode chip reaches 1mW/cm^2. Unlike gas lasers, since laser diode beams are divergent, uncollimated laser diode beams are fairly safe at a laser diode. For observing laser beams, ALWAYS use safety goggles that block infrared rays. Usage of IR scopes, IR cameras and fluorescent plates is also recommended for monitoring laser beams safely.

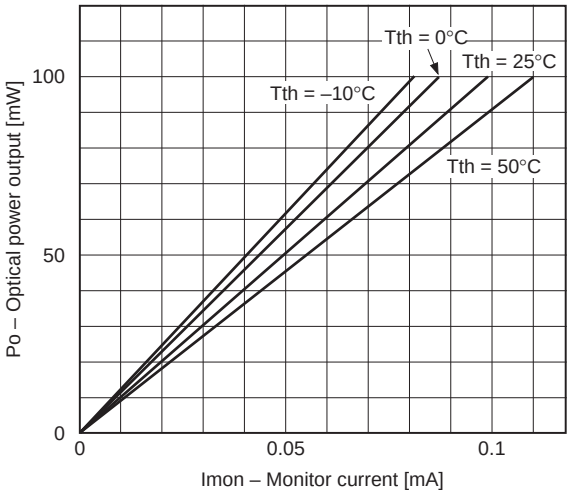


Example of Representative Characteristics

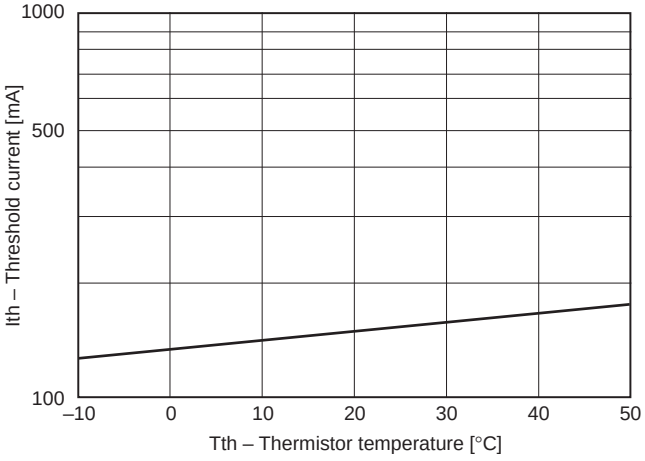
Optical power output vs. Forward current characteristics



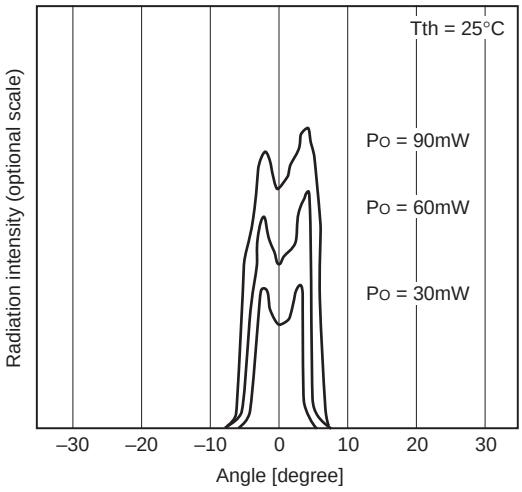
Optical power output vs. Monitor current characteristics



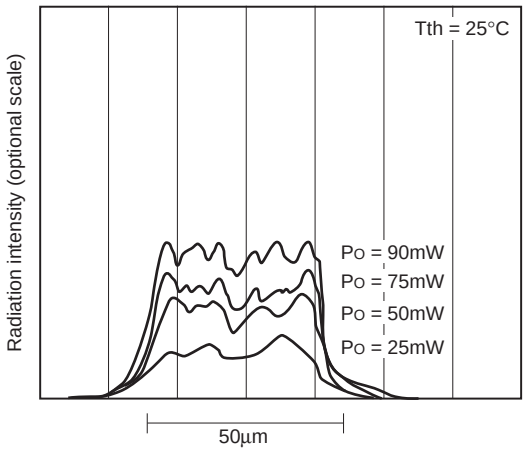
Threshold current vs. Temperature characteristics



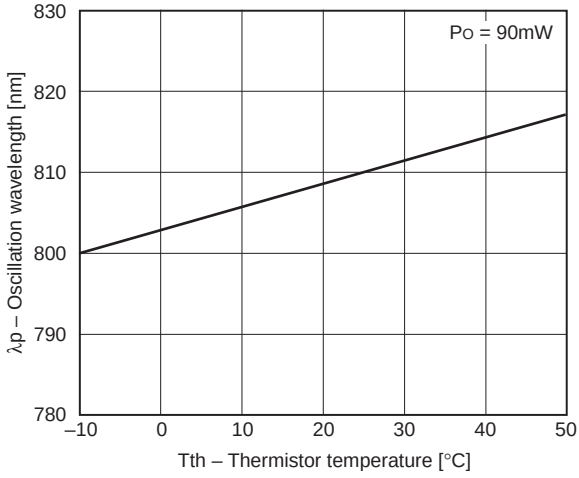
Power dependence of far field pattern (parallel to junction)



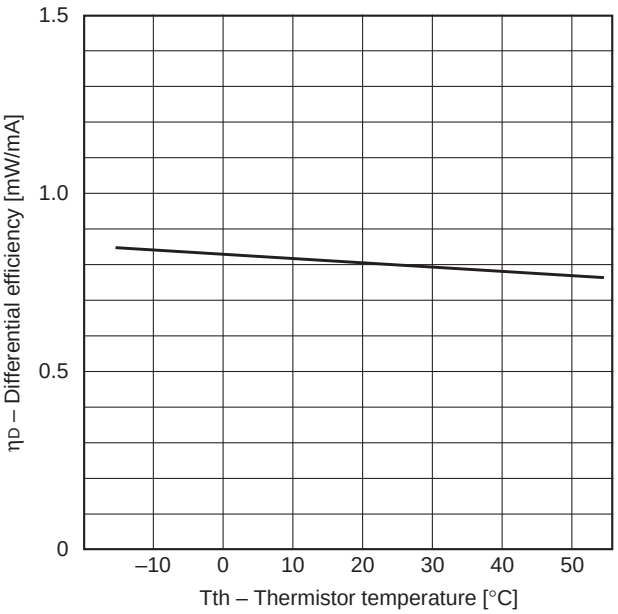
Power depecdence of near field pattern



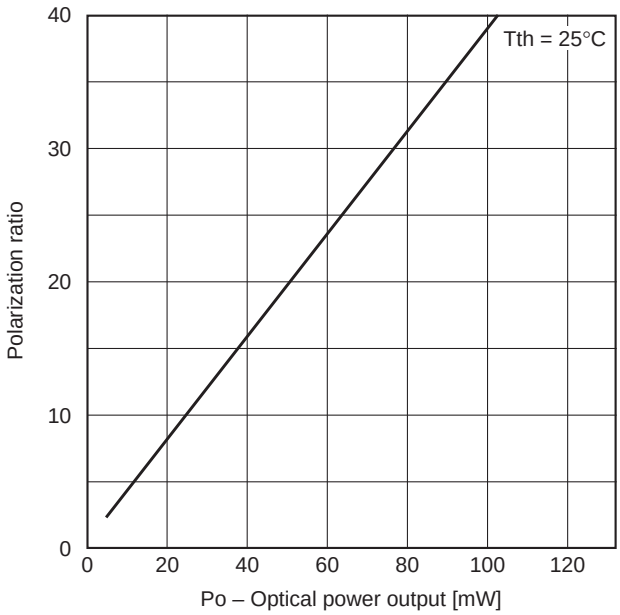
Oscillation wavelength vs. Temperature characteristics



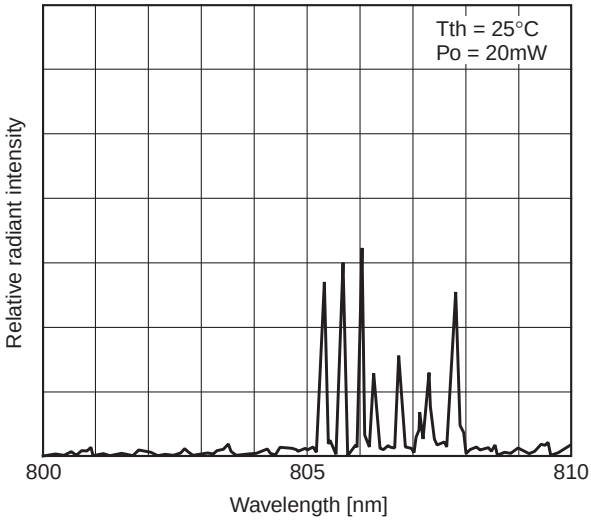
Differential efficiency vs. Temperature characteristics

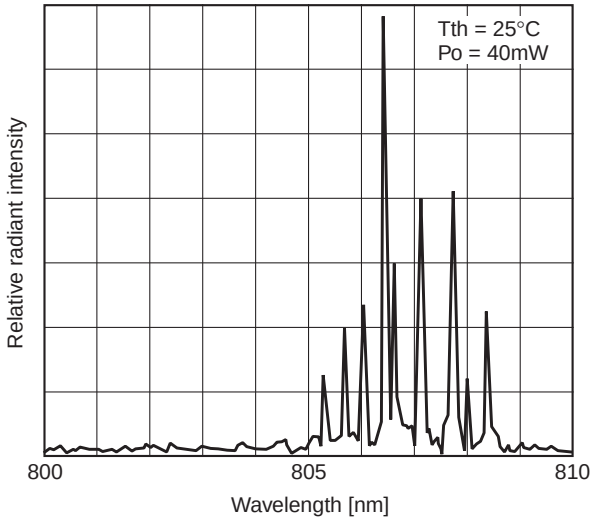


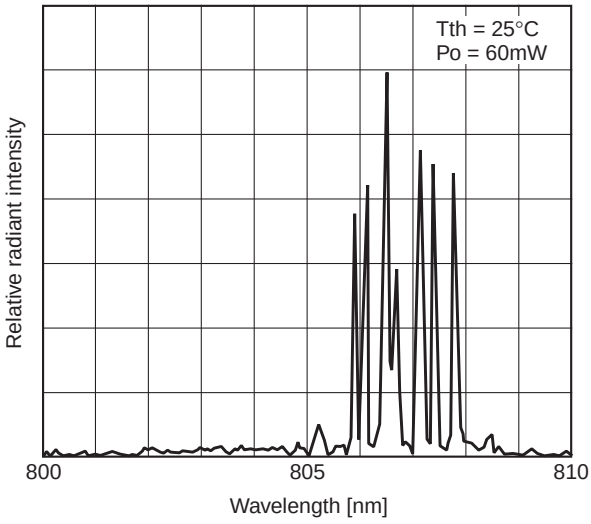
Power dependence of polarization ratio

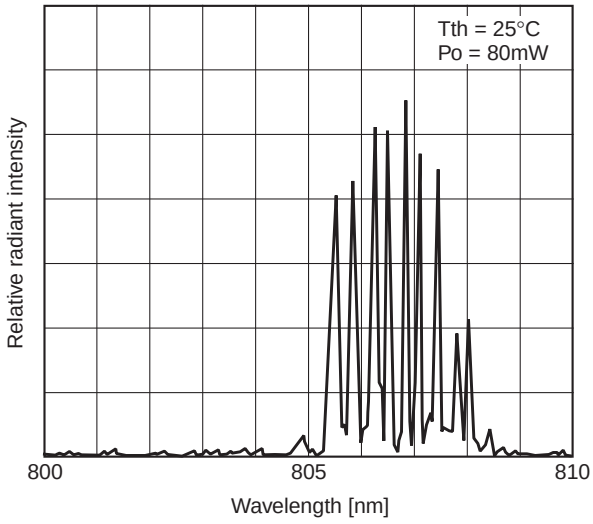


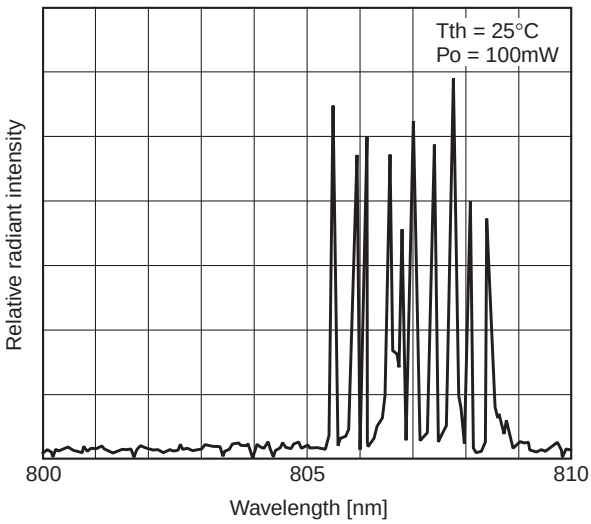
Power dependence of wavelength



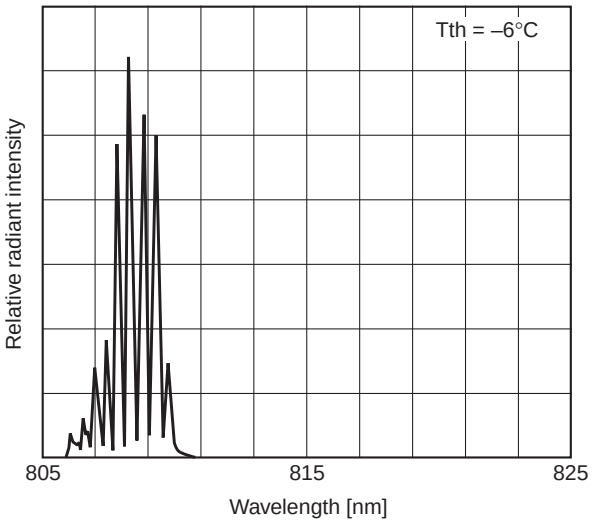


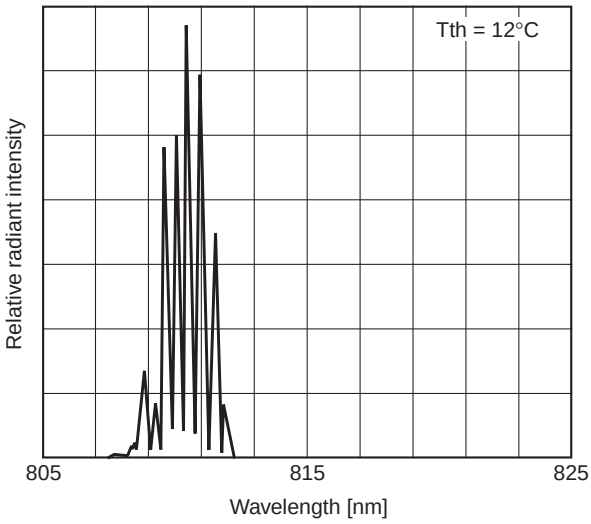


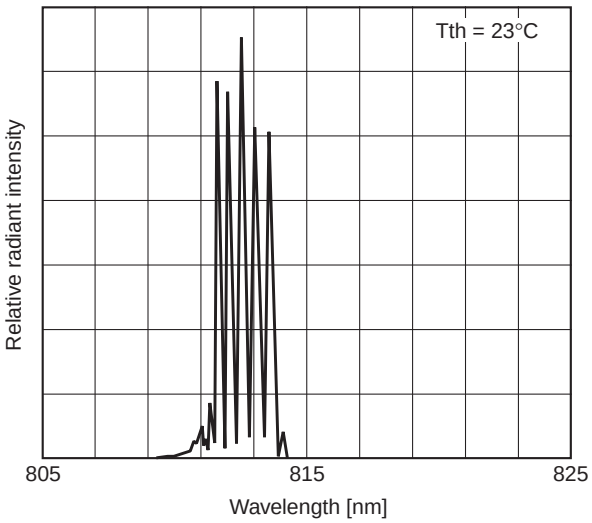


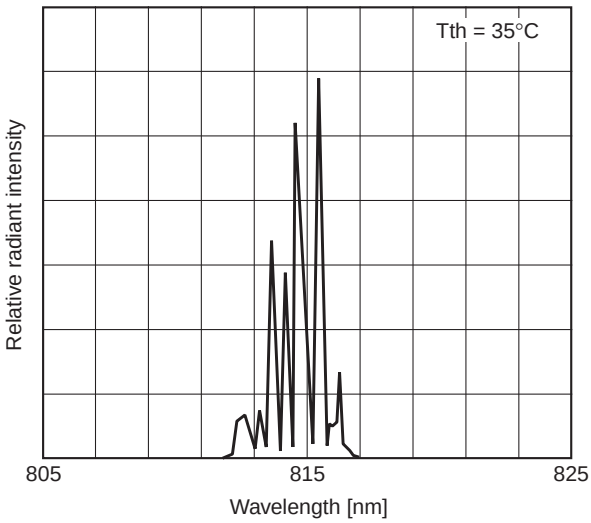


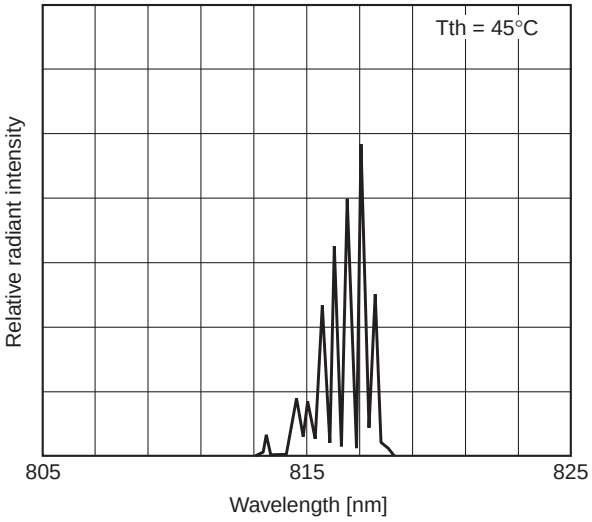
Temperature dependence of wavelength (Po = 90mW)





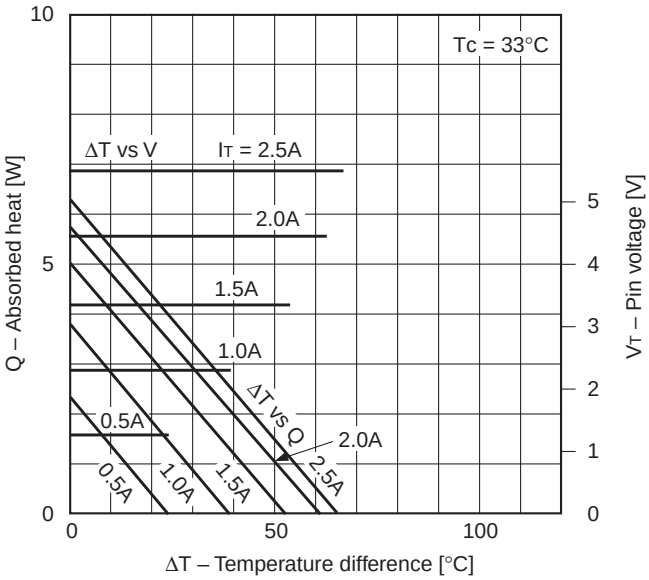




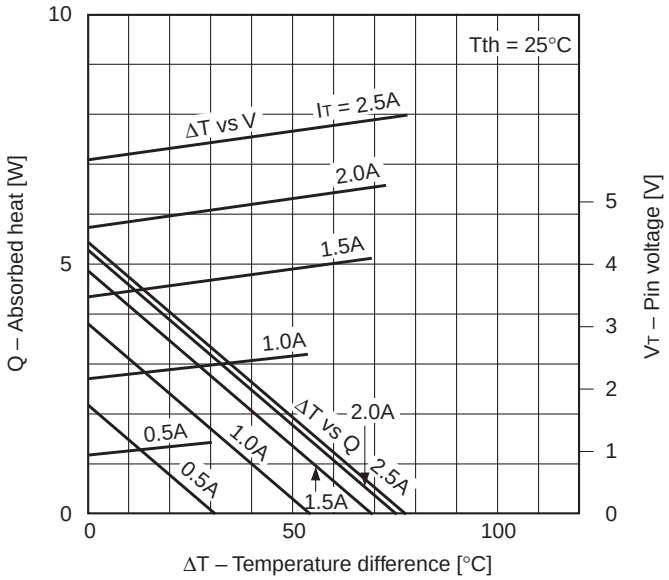


TE cooler characteristics

TE cooler characteristics 1

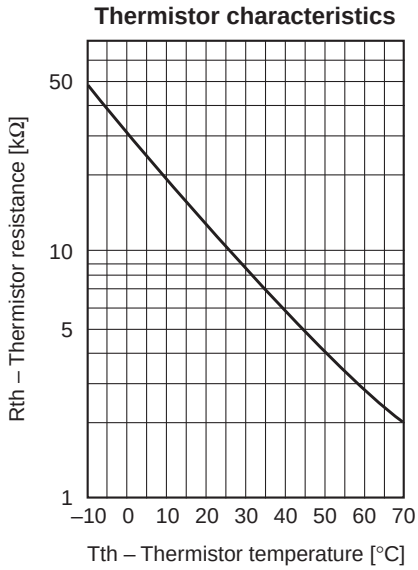


TE cooler characteristics 2



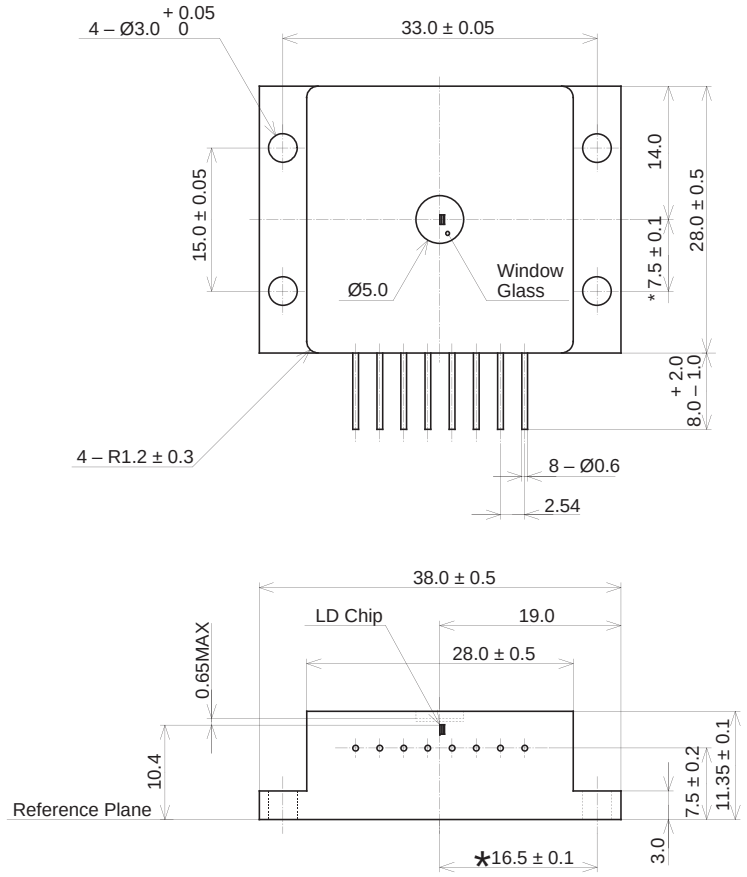
ΔT : Tc – Tth
Tth : Thermistor temperature
Tc : Case temperature

Thermistor characteristics



Package Outline Unit: mm

M – 273(LO – 10)



*Distance between pilot hole and emittng area

PACKAGE STRUCTURE

SONY CODE	M-273(LO-10)
EIAJ CODE	————
JEDEC CODE	————

PACKAGE WEIGHT	43g